

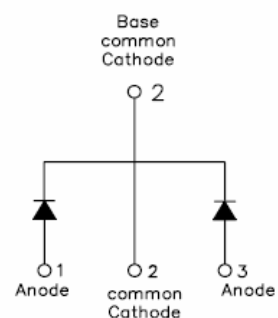
## MUR1560CT ULTRAFAST PLASTIC RECTIFIER

### Applications:

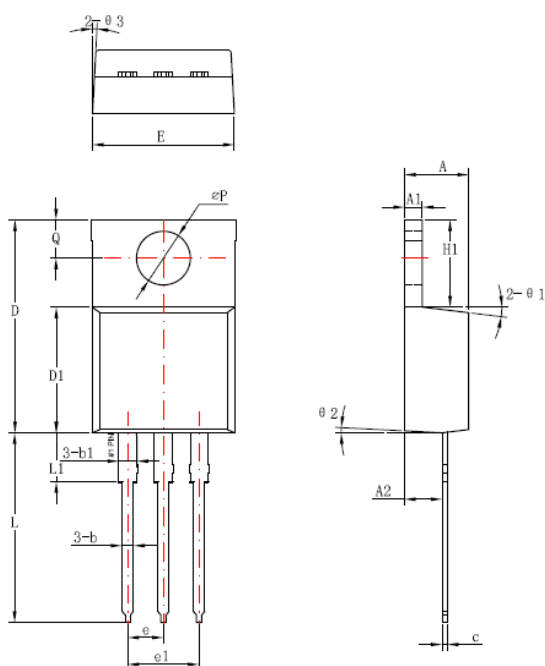
- Switching Power Supply
- Power Switching Circuits
- General Purpose

### Features:

- Ultra-Fast Switching
- High Current Capability
- Low Reverse Leakage Current
- High Surge Current Capability
- Plastic Material has UL Flammability Classification 94V-0
- This is a Pb – Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

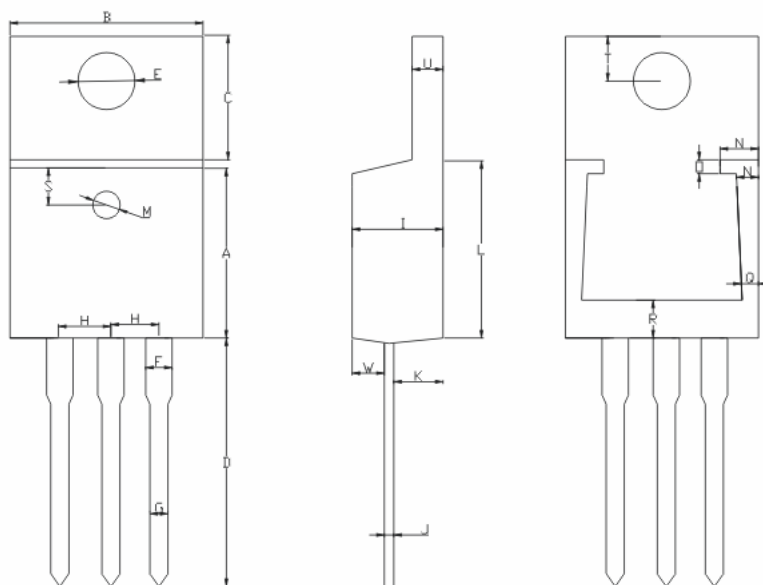


### Mechanical Dimensions: In mm



Symbol	Dimensions in millimeters		
	Min	Typical	Max
A	4.42	4.57	4.72
A1	1.17	1.27	1.37
A2	2.59	2.69	2.89
b	0.71	0.81	0.96
b1		1.27	
c	0.36	0.38	0.61
D	14.94	15.24	15.54
D1	8.85	9.00	9.15
E	10.01	10.16	10.31
e		2.54	
e1		5.06	
H1	6.04	6.24	6.44
L	12.7	13.56	13.78
L1		3.5	
ΦP	3.74	3.84	4.04
Q	2.54	2.74	2.94
Θ1		7°	
Θ2		3°	
Θ3		4°	

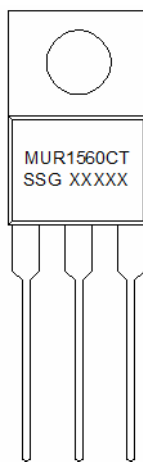
### OPTION1



A: $8.5 \pm 0.5$	B: $9.5 \pm 0.5$	C: $6.4 \pm 0.5$	D: $14.1 \pm 1$
E: $3.84 \pm 0.03$	F: $1.27 \pm 0.03$	G: $0.85 \pm 0.10$	H: $2.54 \pm 0.025$
I: $4.6 \pm 0.5$	J: $0.38 \pm 0.015$	K: $2.75 \pm 0.25$	L: $9.0 \pm 0.5$
M: $1.5 \pm 0.05$	N: $1.8 \pm 0.05$	O: $0.5 \pm 0.05$	P: $1.2 \pm 0.05$
Q: $0.9 \pm 0.05$	R: $3.2 \pm 0.05$	S: $1.55 \pm 0.05$	T: $2.8 \pm 0.15$
U: $1.27 \pm 0.05$	W: $1.27 \pm 0.03$		

**OPTION 2 (SR)**

**TO-220AB**

**Marking Diagram:**


Where XXXXX is YYWWL

MUR	= Device Type
15	= Forward Current (15A)
60	= Reverse Voltage (600V)
CT	= Configuration
SSG	= SSG
YY	= Year
WW	= Week
L	= Lot Number

**Cautions:** Molding resin  
 Epoxy resin UL:94V-0

**Ordering Information:**

Device	Package	Shipping
MUR1560CT	TO-220AB (Pb-Free)	50pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

**Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	$V_{RWM}$	-	600	V
Max. Average Forward	$I_{F(AV)}$	50% duty cycle @Tc=100°C, rectangular wave form	15	A
Max. Peak One Cycle Non-Repetitive Surge Current (Per leg)	$I_{FSM}$	8.3ms, Half Sine pulse	110	A

**Electrical Characteristics:**

- Weiqi Street, Airport Development Zone, Jiangning District, Nanjing, China 211113 ☎ (86) 25-87123907 •
- FAX (86) 25-87123900 • World Wide Web Site - <http://www.sangdest.com.cn> • E-Mail Address - [sales@sangdest.com.cn](mailto:sales@sangdest.com.cn) •



Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop* (per leg)	$V_{F1}$	@ 7.5A, Pulse, $T_J = 25^\circ\text{C}$	2.2	V
	$V_{F2}$	@ 7.5A, Pulse, $T_J = 125^\circ\text{C}$	2.0	V
Max. Reverse Current*	$I_{R1}$	@ $V_R = \text{rated } V_R$ $T_J = 25^\circ\text{C}$	5.0	$\mu\text{A}$
	$I_{R2}$	@ $V_R = \text{rated } V_R$ $T_J = 125^\circ\text{C}$	50	$\mu\text{A}$
Max. Reverse Recovery Time	$t_{rr}$	$I_F=500\text{mA}$ , $I_R=1\text{A}$ , and $I_{rm}=250\text{mA}$	50	ns

\* Pulse width < 300  $\mu\text{s}$ , duty cycle < 2%

### Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature	$T_J$	-	-55 to +150	$^\circ\text{C}$
Max. Storage Temperature	$T_{stg}$	-	-55 to +150	$^\circ\text{C}$
Maximum Thermal Resistance Junction to Case	$R_{\theta JC}$	DC operation	2.0	$^\circ\text{C/W}$
Approximate Weight	wt	-	2	g
Case Style	TO-220AB			

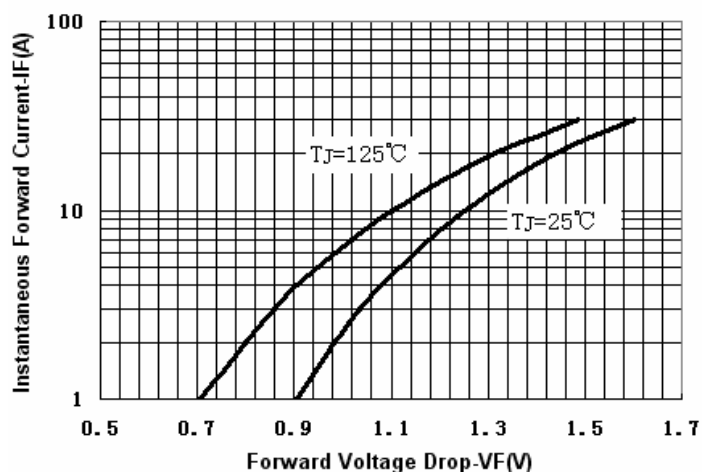


Fig.1-Typical Forward Voltage Drop Characteristics

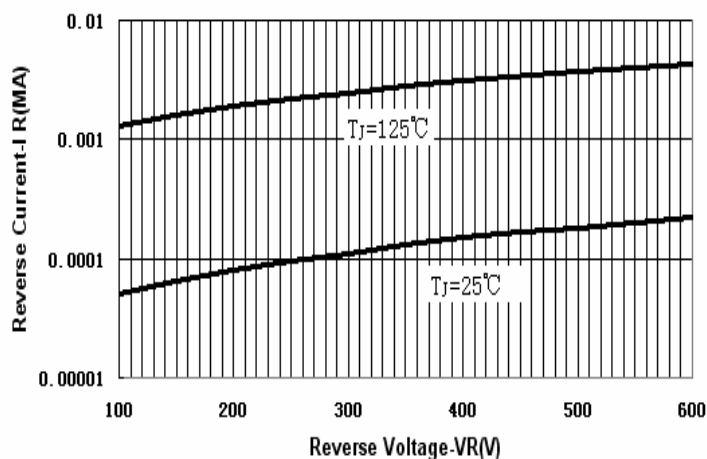


Fig.2-Typical Values of Reverse Current Vs. Reverse Voltage

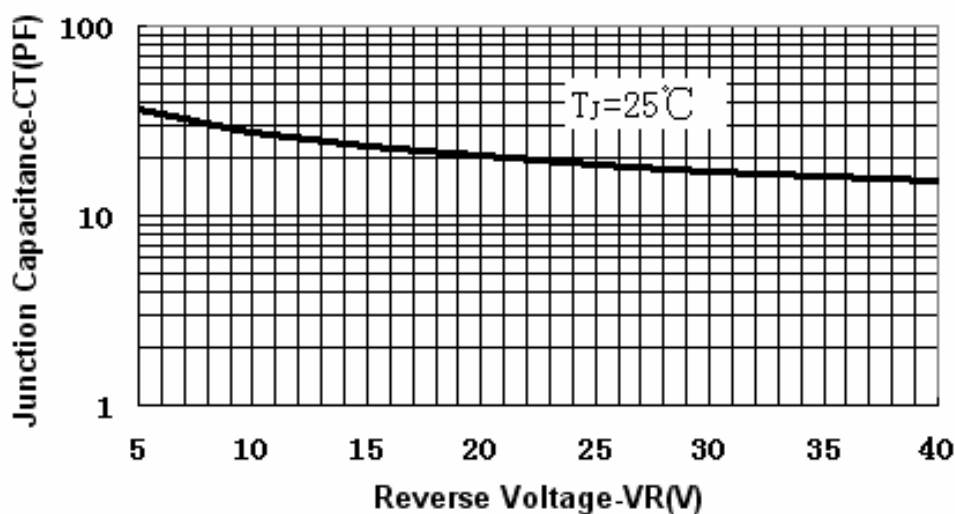


Fig.3-Typical Junction Capacitance Vs.Reverse Voltage



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